

Fast Kickers at DESY

- Injection / ejection in a TESLA like DR
- Generation of a pulse with a pulse length of 12ns
- Measurement at TTF 2
- Full power test
- Measurements at ATF
- XFEL activity

Talk given by Hans Weise

Work done by Frank Obier

TESLA like damping ring- injection / ejection

System Specification

15 – 30 kicker

- Pulse voltage <7.5kV
- Pulse current 100A
- Pulse length 40ns
- Rise time (10%-90%) 8ns
- Micro pulse repetition rate 3MHz
- Marko pulse repetition rate 5Hz
- Amplitude stability ($1/10 \sigma_x$) 0.05%
- Residual kick 0.5%
- Number of pulses 2820

Achieved Performance

(single kicker)

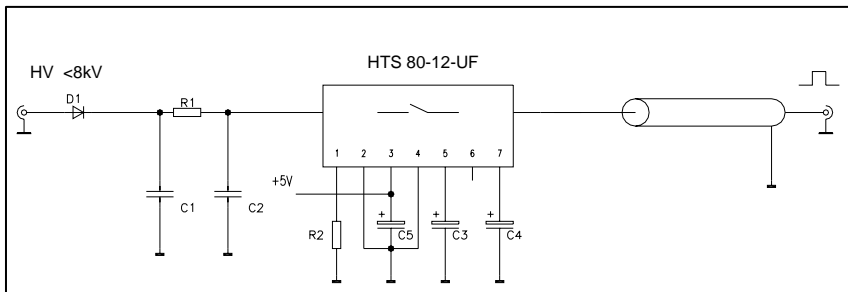
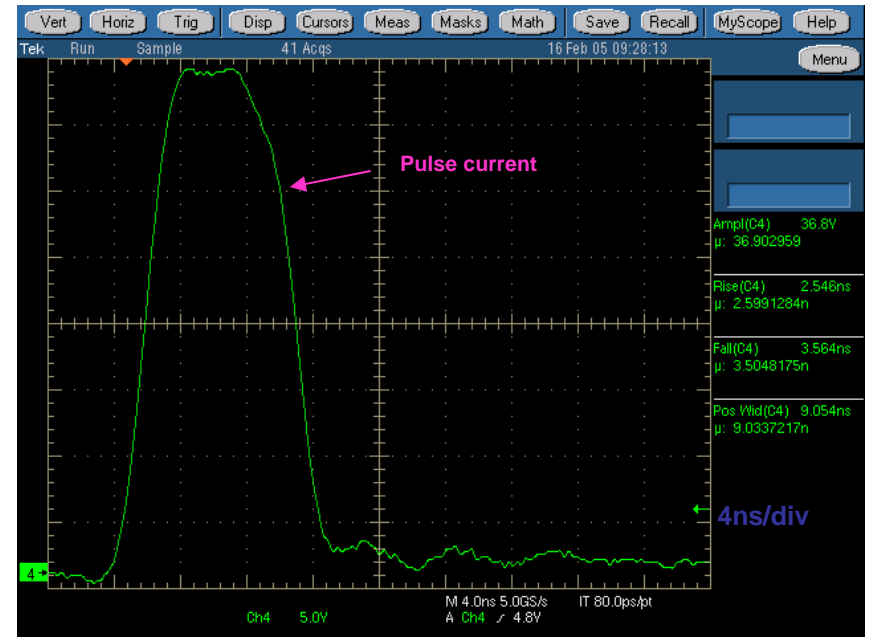
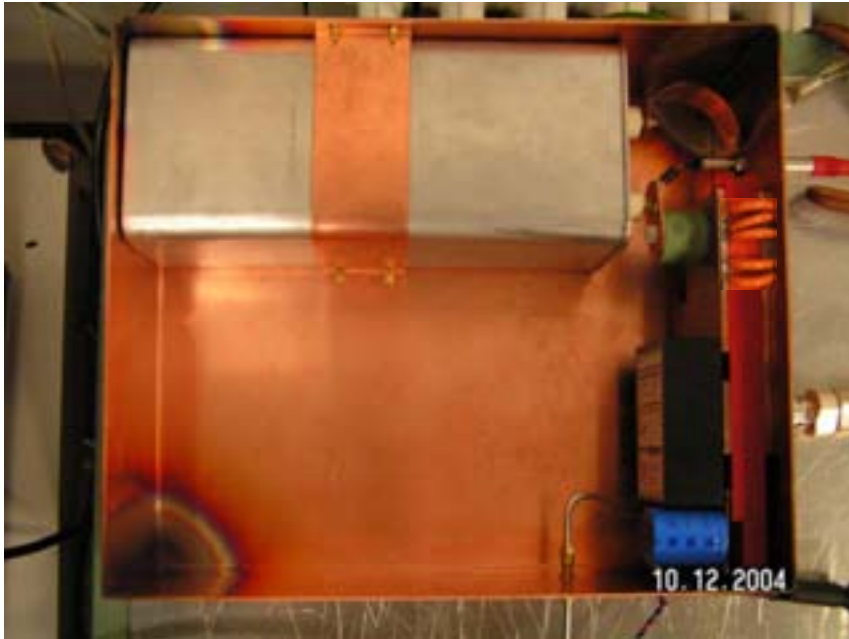
- 6.5 kV
- 76 A (68A)
- 12ns
- 4.9ns
- 3MHz
- 5Hz
- 0.3%
- 0.68%
- 3000

Next Steps

- improve power-supply
- apply clipping techniques
- beam based correction

- Behlke switches with $t_{on} = 5ns$ and $t_{on} = 10ns$ provide the opportunity to shorten the damping ring. Further measurements are foreseen.

Generation of pulse with a pulse length of 12ns



- principle set up of the pulser
- Behlke switch built in Mosfet technology
- max. 1000 single pulses with 1μs spacing

Behlke switch data:

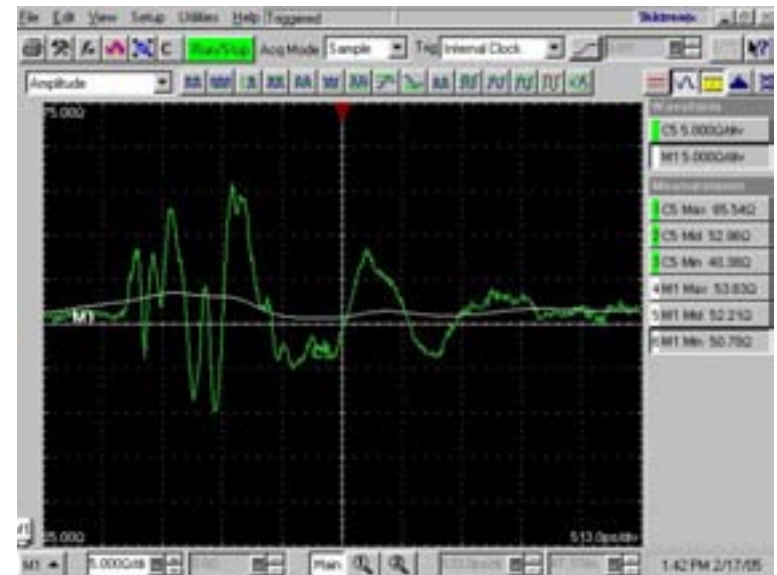
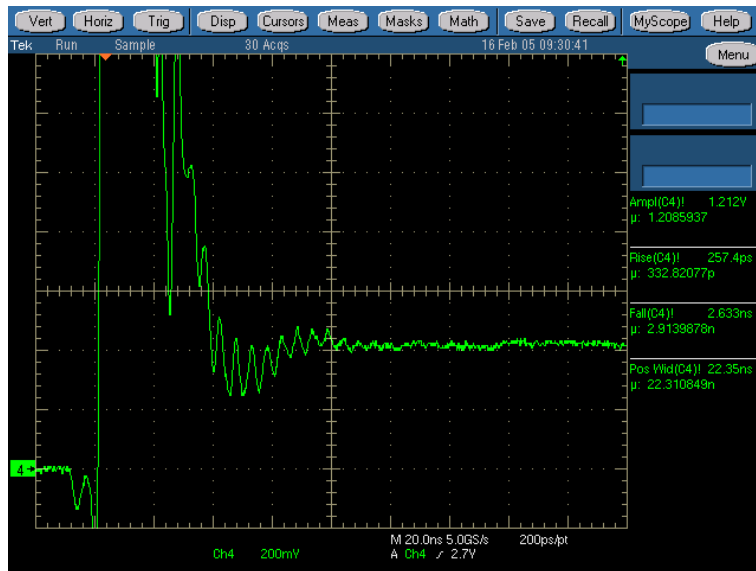
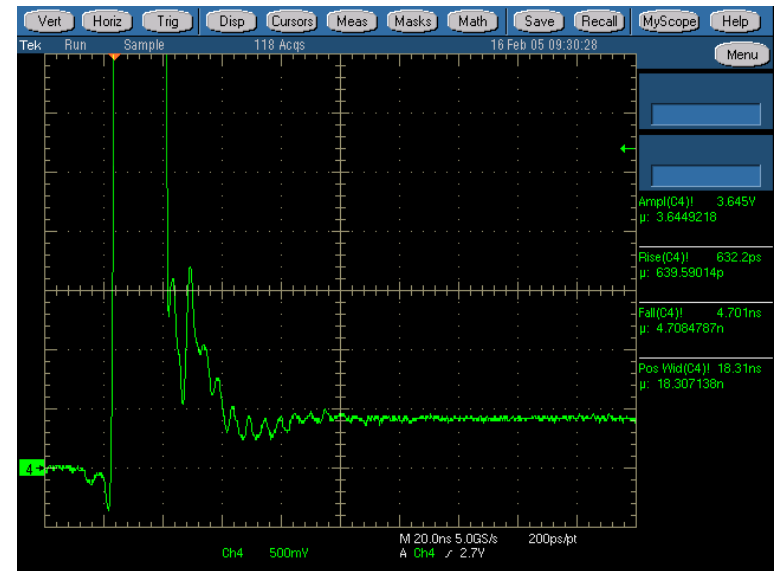
Type	HTS 80-12UF
Pulse voltage	8 kV
Pulse current	120 A (tp<50ns)
Jitter	100 ps
Rise time (10-90%)	2 ns

Pulser data:

Voltage	6.5 kV
Pulse current	73.6 A
Frequency (burst)	1MHz
Number of pulses	1000
Pulse length	12 ns

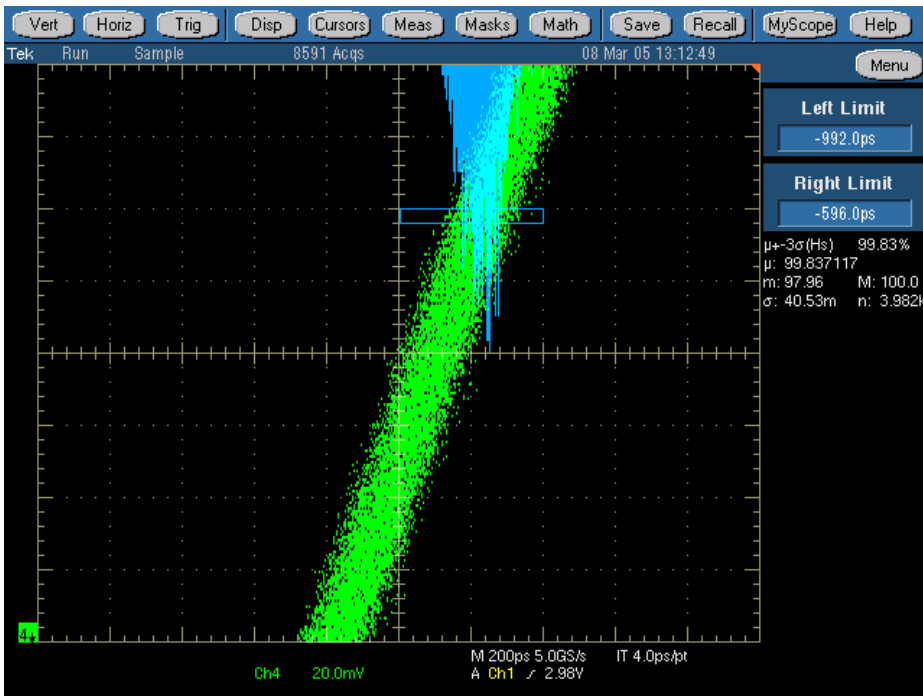
Ripple Measurement

Switch HTS 80-12-UF $t_{on}=10ns$

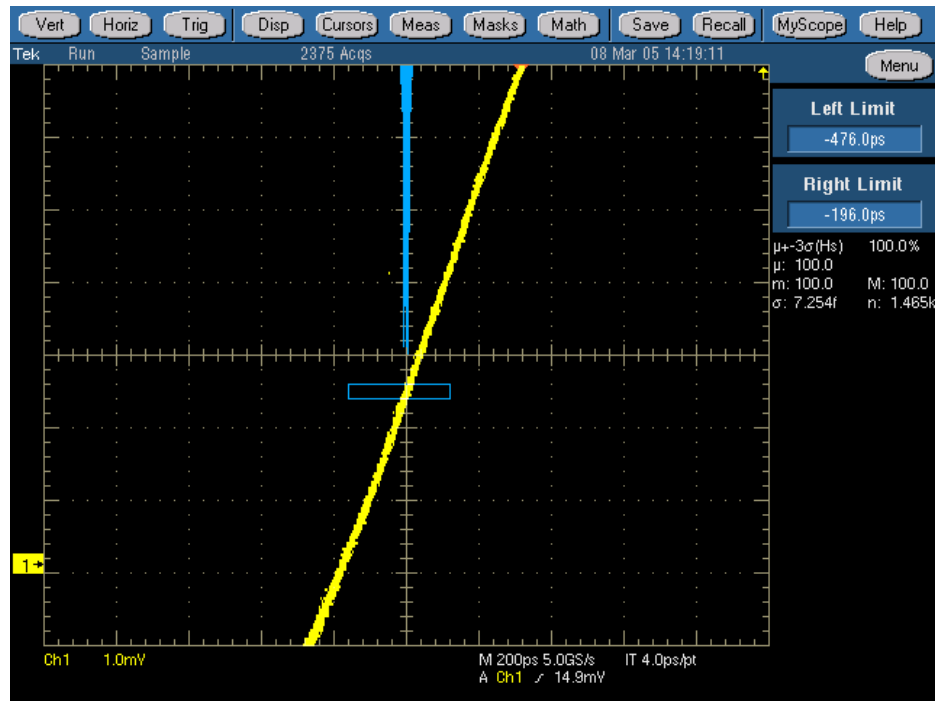


Timing Jitter

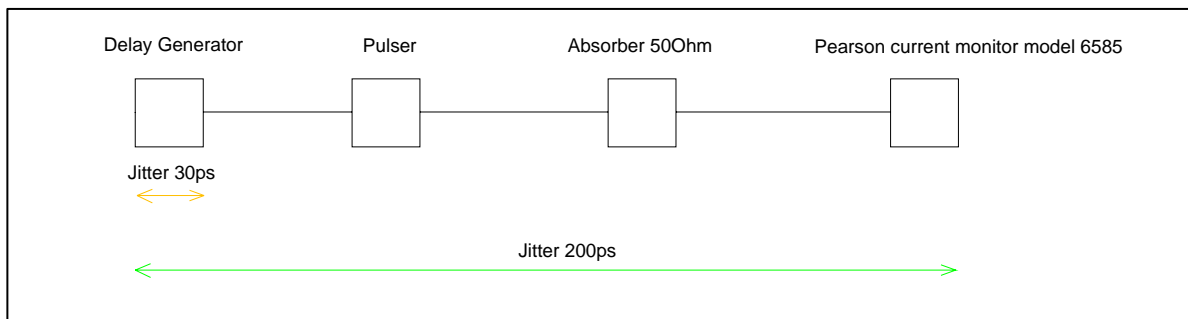
Swicht HTS 80-12UF $t_{on}=10ns$



Channel 1 Trigger (Delay .-Trigger generator) Channel 4 Pulse current with a Jitter of 200ps (Behlke Data: Typical Turn-on Jitter of 100ps)



Channel 1 (Delay.- Trigger generator) Jitter 30ps

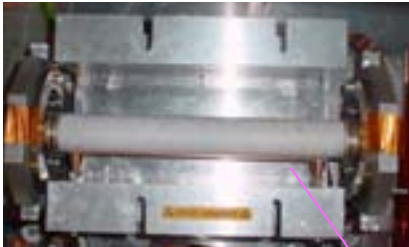


F. Obier / DESY

Pearson Current Monitor Model 6585

Sensitivity	1V/A \pm 1%
50 Ω	0.5V/A into
Output resistance	50 Ω
Max. peak current	500A
Max. rms current	10A
Droop rate	0.8%/μs
Useable rise time	1.5ns
Low frequency 3dB cut-off	400Hz
High frequency \pm 3dB	250MHz

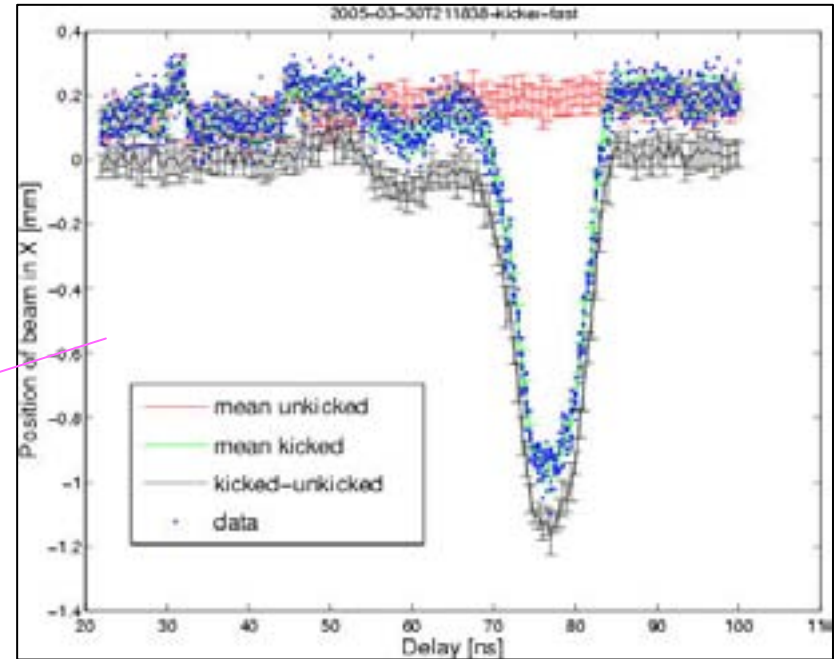
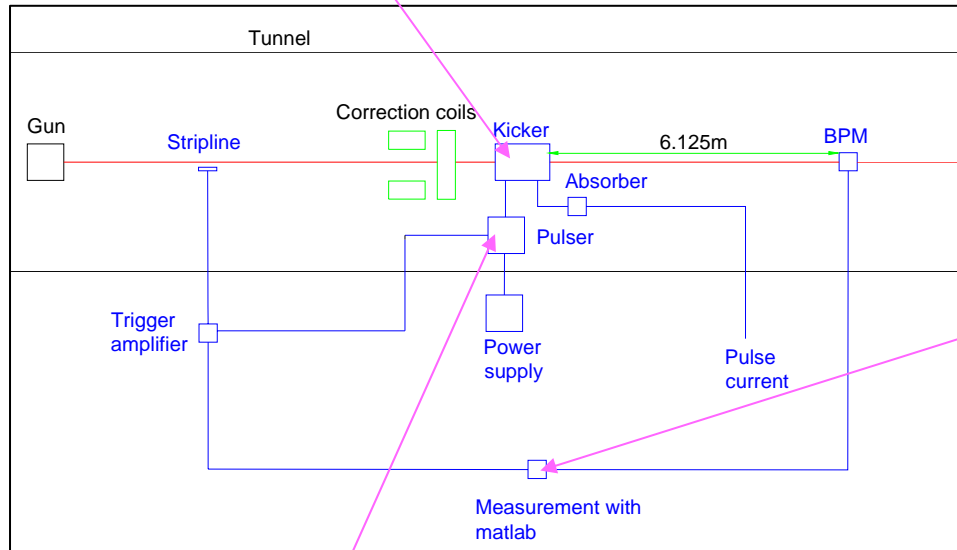
Measurements at TTF 2



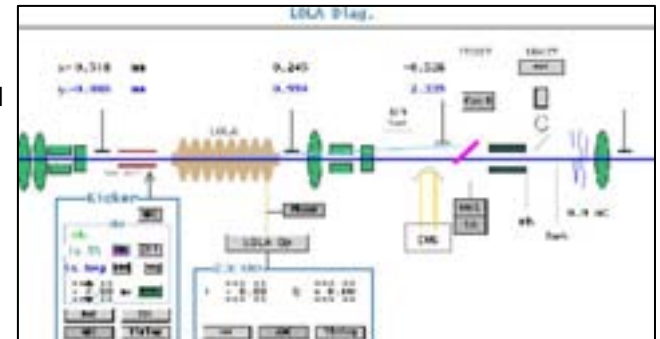
Ceramic Kicker

Data:

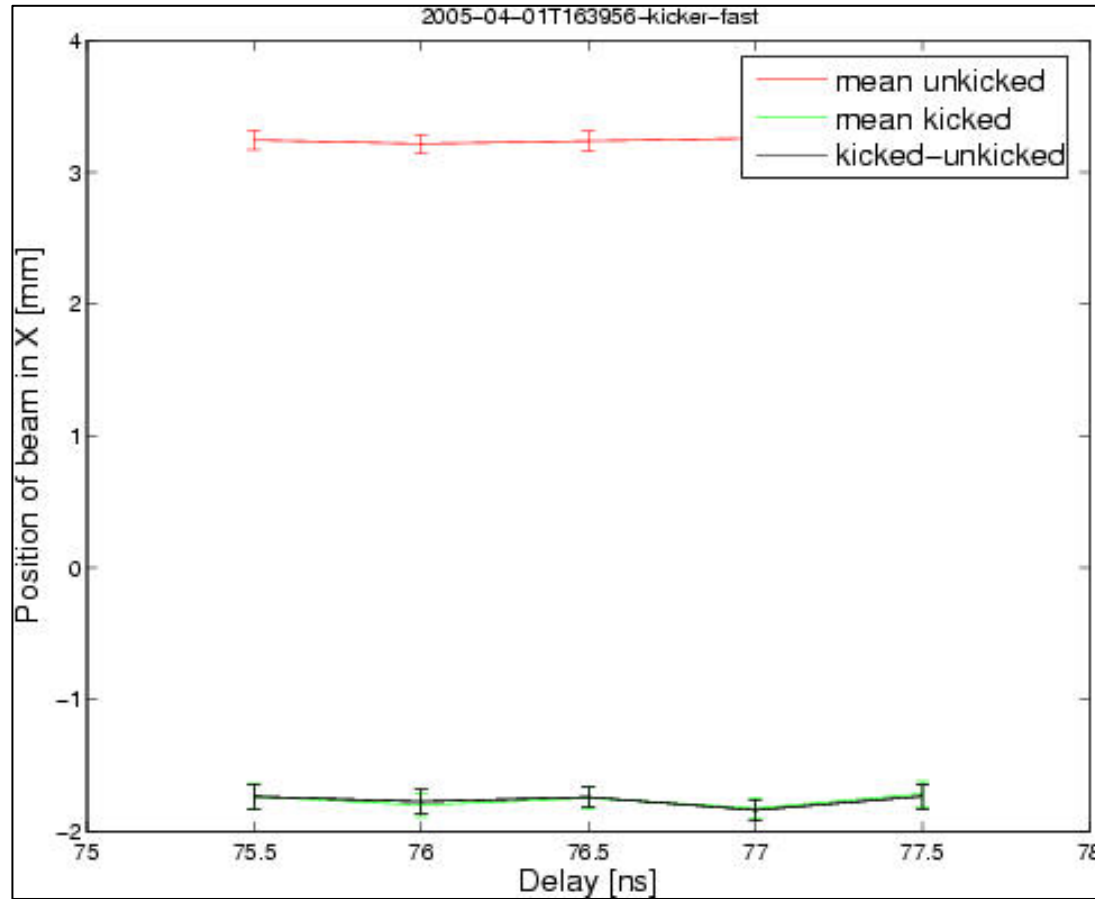
Voltage	7.0 kV
Pulse current	61 A
Pulse length	12 ns



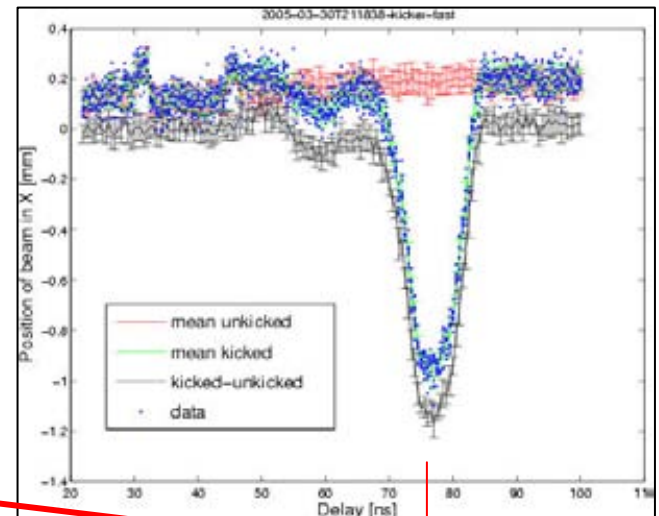
- principle set up of the kicker
- measure the kicker strength
- scan the kicker pulse with a step width of 0.5 ns and taking 20 pulses for each data point.



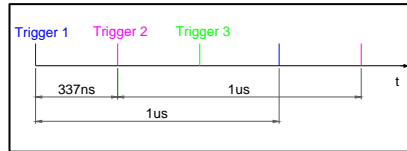
Measurements at TTF 2



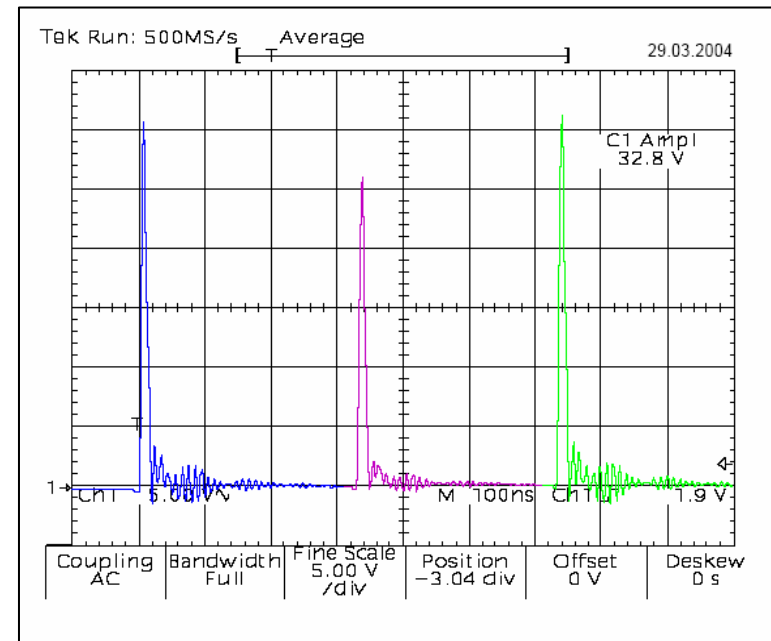
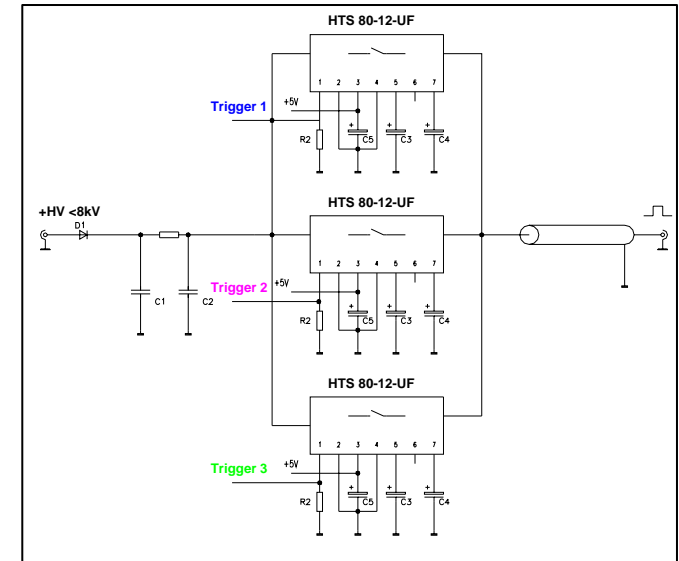
Measurement on kicker 'flat' top to investigate influence of timing jitter. Standard deviations of unkicked / kicked bunch (eposx1/eposx2) are given below as well as relative error. Smallest error as low as 0.5 % at certain delay, relative error increases with distance from 'flat, top. Kicker **HV = 7kV**.



Pulse with a burst frequency of 3MHz



- principle set up of the pulser
- Behlke switch in Mosfet technology
- max. 1000 single pulses with 1 µs spacing



Pulser data:

Voltage	6.5 kV
Pulse current	73.6 A
Frequency (burst)	3 MHz
Number of pulses	3000
Pulse length	12 ns

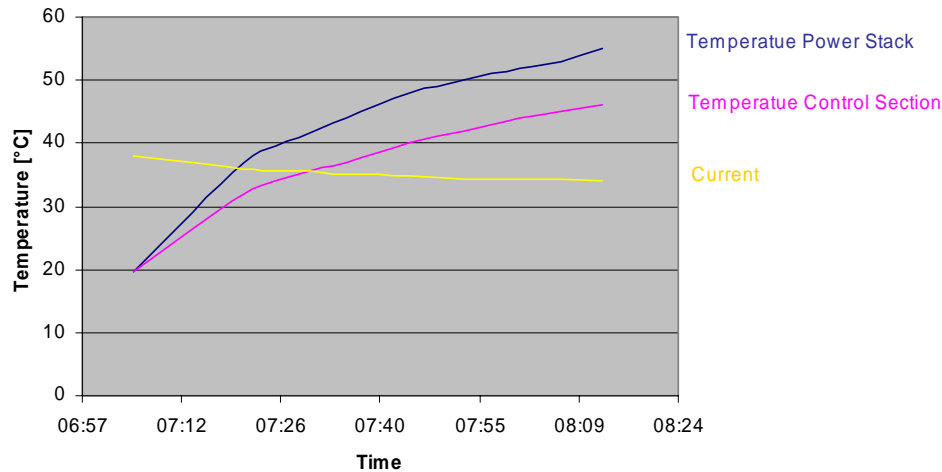
Full power test with a HTS 50-08-UF switch

For this Measurement we have a pulser with three switches HTS 50-08 UF.
Full power test with three Switches 500 single pulses and 1 μ s spacing each.

Voltages	4.5 kV
Current	38 A
Pulse length	8 ns
Rise time (10-90%)	3 ns
Micro pulse repetition rate	3 MHz
Macro pulse repetition rate	1 Hz
Number of pulse	1500



Full Power Test with 4,5kV 5Hz 500 Pulses



Time	Temperature Power Stack [°C]	Temperature control section [°C]	Current [A]
07:05	19,6	19,6	38
07:21	37	32	36
07:29	41	35	35,6
07:36	44	37	35,2
07:45	48	40	34,8
07:53	50	42	34,4
08:01	52	44	34,2
08:07	53	45	34,2
08:13	55	46	34

Absorber Temperature
34°C

Full power test with a HTS 80-12-UF switch

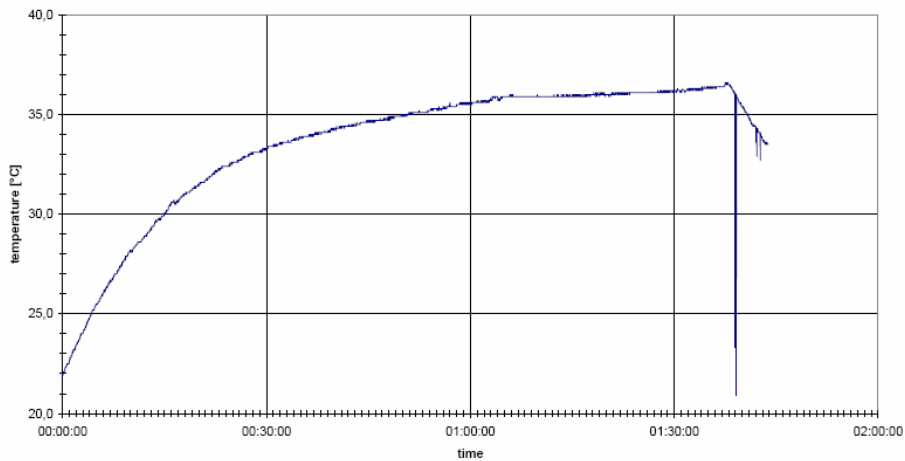
For this Measurement we have a pulser with three switches HTS 80-12 UF. Full power test with three Switches 1000 single pulses and 1 μ s spacing each.

Voltages	6.5 kV
Current	78.5 A
Pulse length	16 ns
Rise time (10-90%)	4 ns
Micro pulse repetition rate	3 MHz
Macro pulse repetition rate	1 Hz /5 Hz
Number of pulse	3000



Absorber Temperature 45°C

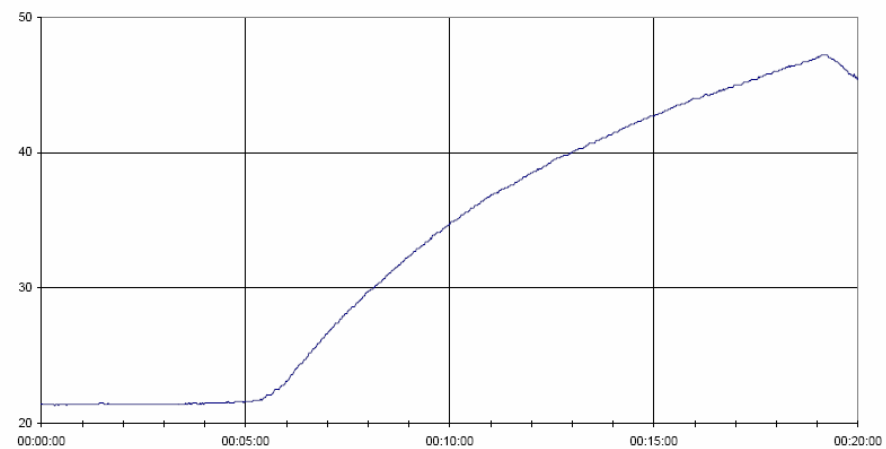
triple switch pulser
pulse train: 3000, 1 MHz, 1 Hz
no cooling, case open



20050421_1007_1Hz.xls\Temperaturverlauf

Absorber Temperature 105°C

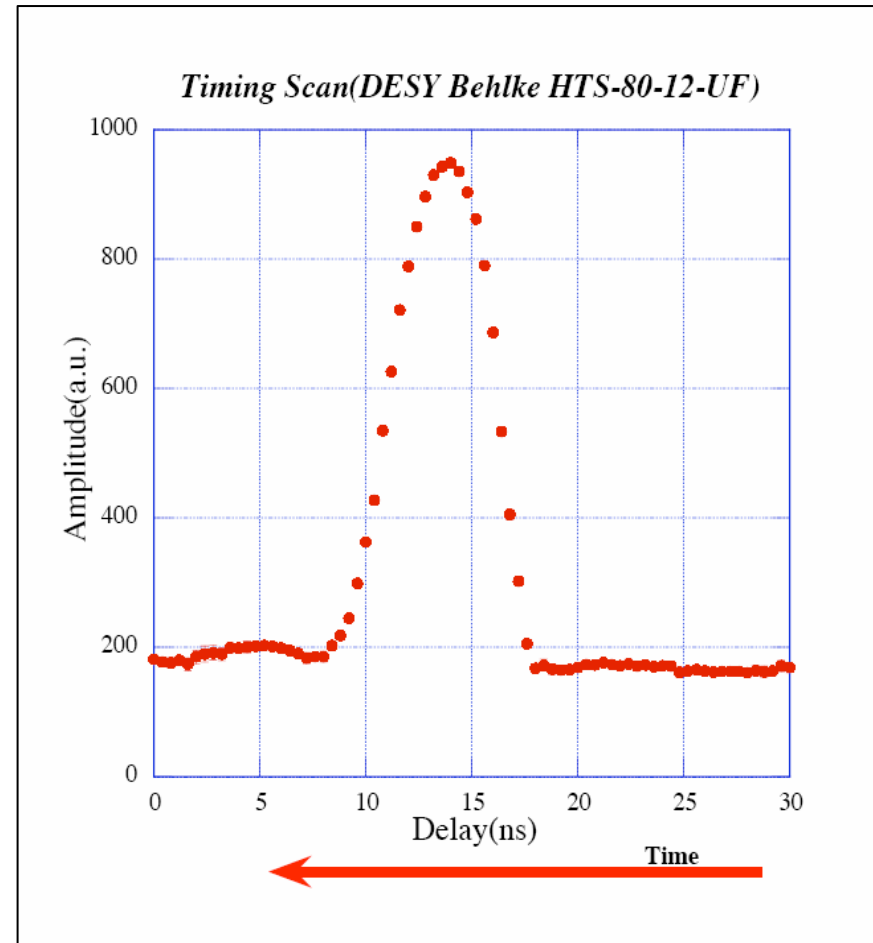
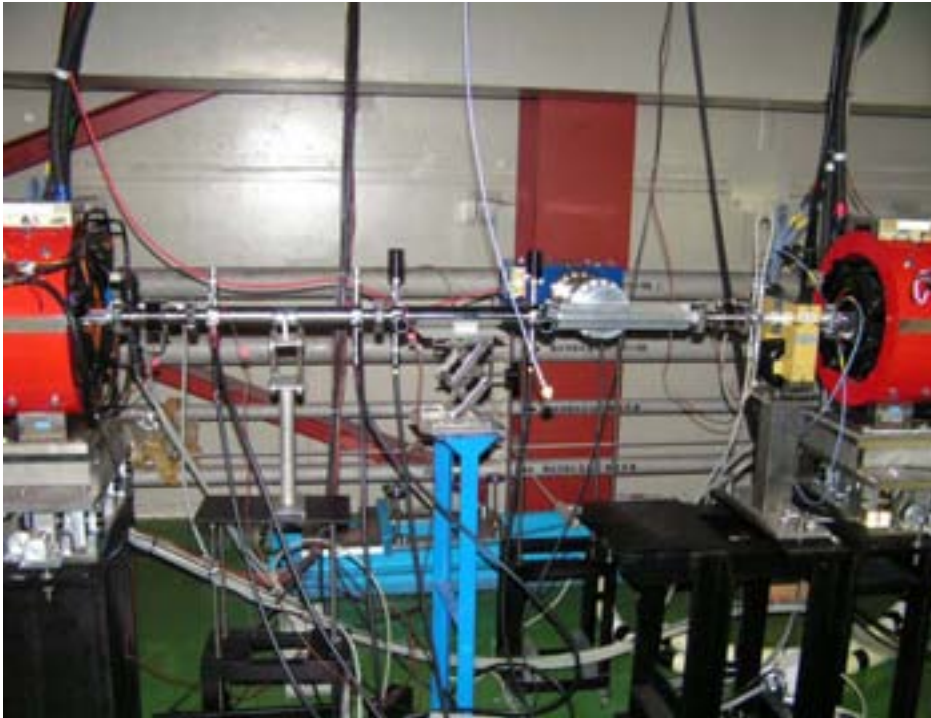
triple switch pulser
pulse train: 3000, 1 MHz, 5Hz
forced air cooling, case open



20050421_1457_5Hz.xls\Temperaturverlauf

Measurement at KEK ATF Ring

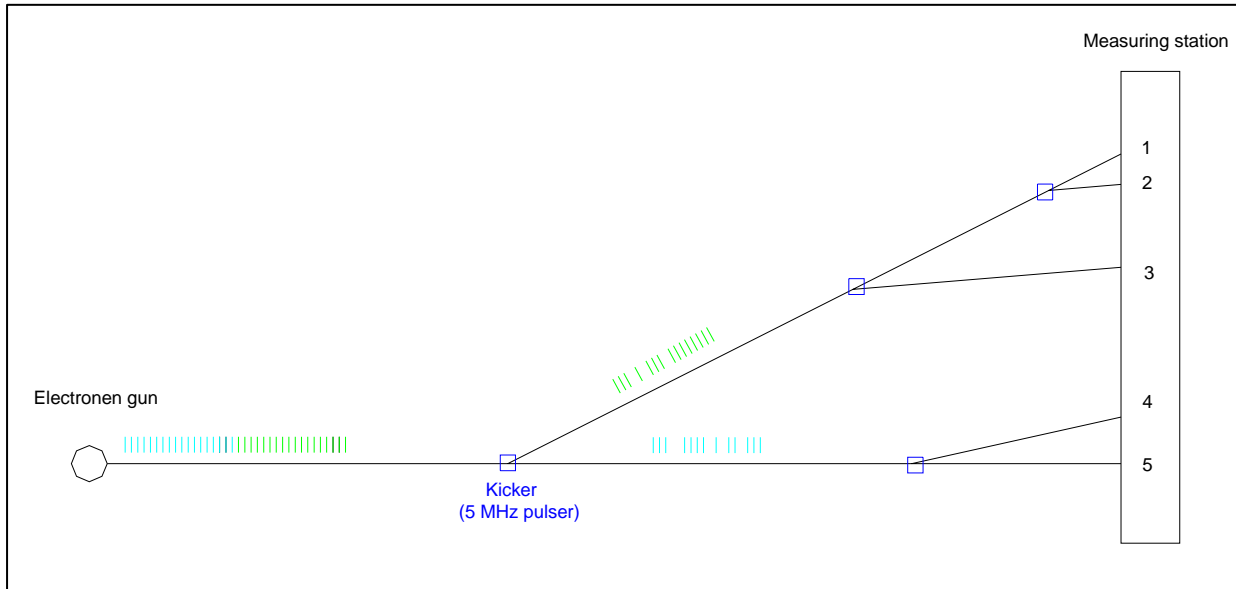
The beam kick is observed by a turn-by turn BPM as the amplitude of the oscillation of the betatron frequency.
The kick effect is measured by scanning the pulse timing for the beam timing.



Next steps:

New Behlke switches with a water cooling and with selected Mosfet semiconductor are ordered (delivery date 08/05).
Investigate the pulse to pulse stability and the long-term stability (temperature drift) of a 3MHz pulser.

XFEL activities



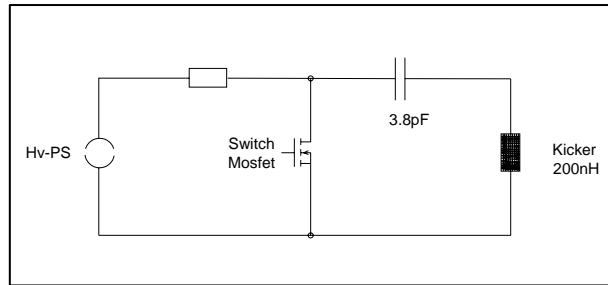
For this beam distribution we need a 5 MHz pulser with following data:

		XFEL
Energy	GeV	20
Deflection angle	mrاد	0,3
Rep. Rate Macro pulse	Hz	10
Rep. Rate Bunch	MHz	5
Pulse Width	ns	200
Bdl	mTm	12
Accuracy		5e-5
Ripple		5e-5
Bunch spacing	ns	200
Pulse structure		burst
Amplitude		variable

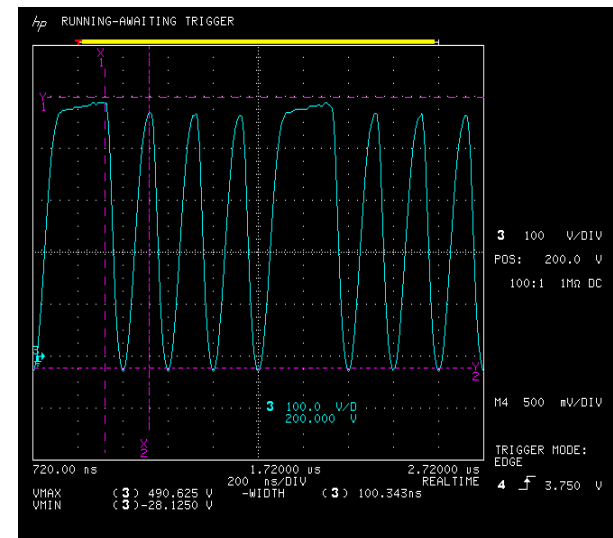
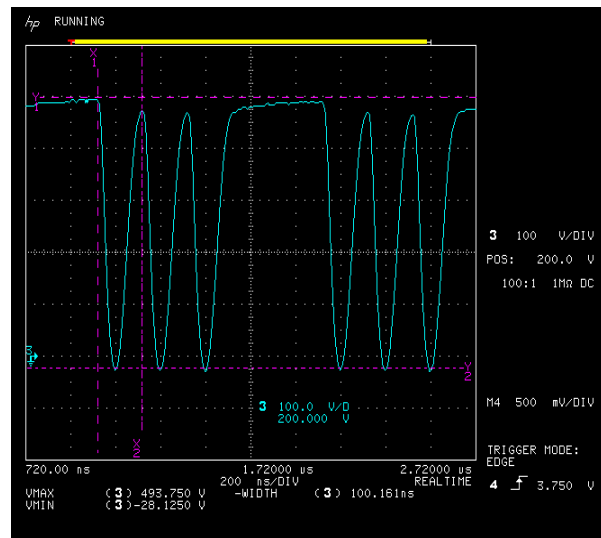
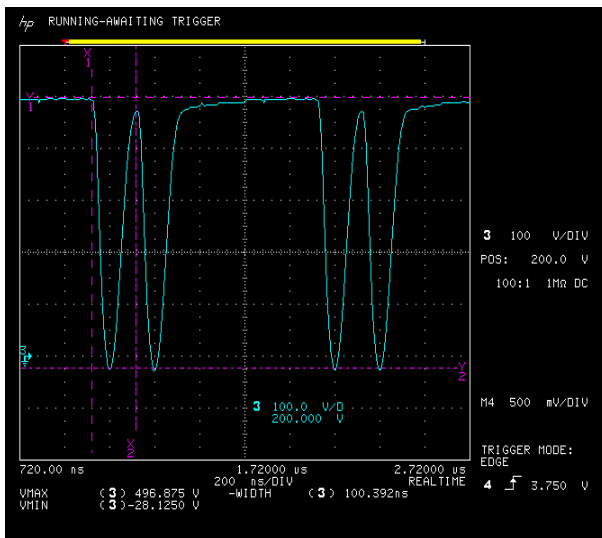
Next steps:

- New Behlke switches with a rep. rate of 5 MHz (delivery date unknown) are under development at the company. We expect a rectangular current pulse.
- The alternative: a pulser with 5 parallel HTS 80-12 UF switches.
- Or use a pulser with single semiconductors (Directed Energy, Inc. DE-150 102N02A). Pulse form: a sinus half-wave.

XFEL activities

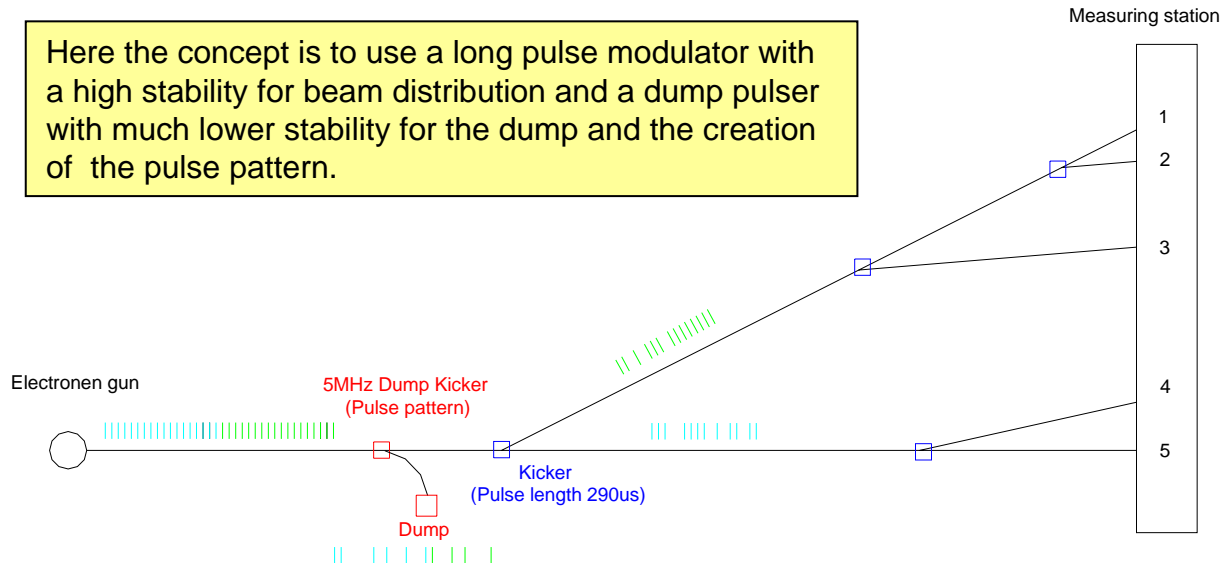


- principle set up of the pulser
- Directed Energy, Inc. Mosfet DE-150 102N02A
- Generate single pulses with 200ns spacing



XFEL activities

Here the concept is to use a long pulse modulator with a high stability for beam distribution and a dump pulser with much lower stability for the dump and the creation of the pulse pattern.



For this beam distribution we need a long pulse modulator with following data:

		XFEL
Energy	GeV	20
Deflection angle	mrad	0,3
Rep. Rate Macro pulse	Hz	10
Rep. Rate Bunch	MHz	5
Pulse Width	μ s	290
Bdl	mTm	12
Accuracy		5e-5
Ripple		5e-5
Total length	m	10
Gap height	mm	10-50
Bunch spacing	ns	200

